

PC817XJ0000F Series

*4-channel package type is also available. (model No. **PC847XJ0000F Series**)

DIP 4pin General Purpose Photocoupler



■ Description

PC817XJ0000F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5.0kV.

Collector-emitter voltage is 80V and CTR is 50% to 600% at input current of 5mA.

■ Features

- 1. 4pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}:80V)
- 4. Current transfer ratio (CTR : MIN. 50% at $I_F=5$ mA, $V_{CF}=5V$)
- 5. Several CTR ranks available
- 6. High isolation voltage between input and output $(V_{iso(rms)}: 5.0 \text{ kV})$
- 7. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

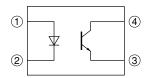
- Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC817)
- 2. Package resin : UL flammability grade (94V-0)

■ Applications

- 1. I/O isolation for MCUs (Micro Controller Units)
- 2. Noise suppression in switching circuits
- 3. Signal transmission between circuits of different potentials and impedances



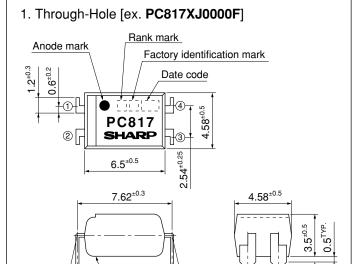
■ Internal Connection Diagram



- 1 Anode
- 2 Cathode
- 3 Emitter
- 4 Collector

■ Outline Dimensions

(Unit:mm)



Epoxy resin $\theta : 0 \text{ to } 13^{\circ}$

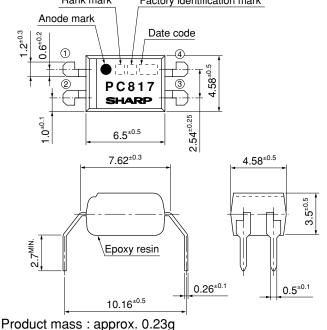
Product mass: approx. 0.23g

2. SMT Gullwing Lead-Form [ex. PC817XIJ000F] Rank mark Anode mark Factory identification mark Date code $.58^{\pm0.5}$ 3 **PC817** SHARP $2.54^{\pm0.25}$ $6.5^{\pm0.5}$ $4.58^{\pm0.5}$ $7.62^{\pm0.3}$ $35^{\pm0.25}$ $3.5^{\pm0.5}$.26^{±0.1} Epoxy resin 2.54^{±0.25} 1.0+0.4 $1.0^{+0.4}_{-0}$ $10.0^{+0}_{-0.5}$

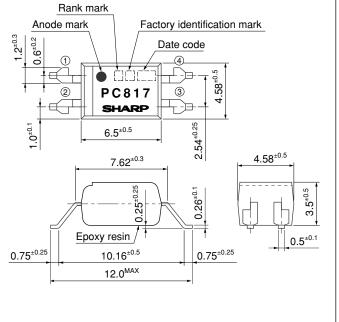
Product mass: approx. 0.22g

Product mass: approx. 0.22g

3. Wide Through-Hole Lead-Form [ex. **PC817XFJ000F**] Rank mark Factory identification mark



4. Wide SMT Gullwing Lead-Form [ex. PC817XFPJ00F]



Sheet No.: D2-A03102EN



Date code (2 digit)

	1st o	digit		2nd digit	
	Year of p	roduction		Month of production	
A.D.	Mark	A.D	Mark	Month	Mark
1990	A	2002	P	January	1
1991	В	2003	R	February	2
1992	С	2004	S	March	3
1993	D	2005	T	April	4
1994	Е	2006	U	May	5
1995	F	2007	V	June	6
1996	Н	2008	W	July	7
1997	J	2009	X	August	8
1998	K	2010	A	September	9
1999	L	2011	В	October	0
2000	M	2012	С	November	N
2001	N	:	:	December	D

repeats in a 20 year cycle

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material	
no mark	Ionon	Sector (Contraction 201)	
	Japan	SnCu (Cu : TYP. 2%)	
	Indonesia	SnBi (Bi : TYP. 2%)	
_	China	SnCu (Cu : TYP. 2%)*	

Rank mark

Refer to the Model Line-up table

^{*} Up to Date code "T4" (April 2005), SnBi (Bi : TYP. 2%).

** This factory marking is for identification purpose only.

Please contact the local SHARP sales representative to see the actural status of the



■ Absolute Maximum Ratings

	■ Absolute Maximum Ratings $(T_a=25^{\circ}C)$							
	Parameter	Symbol	Rating	Unit				
	Forward current	I_F	50	mA				
Input	*1 Peak forward current	I_{FM}	1	A				
Inf	Reverse voltage	V_R	6	V				
	Power dissipation	P	70	mW				
	Collector-emitter voltage	V_{CEO}	80	V				
Output	Emitter-collector voltage	V _{ECO}	6	V				
Out	Collector current	I_C	50	mA				
	Collector power dissipation	P_{C}	150	mW				
	Γotal power dissipation	P _{tot}	200	mW				
*2 I	solation voltage	V _{iso (rms)}	5.0	kV				
Operating temperature		T_{opr}	-30 to +100	°C				
	Storage temperature	T_{stg}	-55 to +125	°C				
*3 €	Soldering temperature	T_{sol}	260	°C				

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

						(1a 25 C)	
Parameter			Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage		V_F	$I_F=20mA$	_	1.2	1.4	V
Peak forward volta	age	V_{FM}	$I_{FM}=0.5A$	_	_	3.0	V
Reverse current		I_R	$V_R=4V$	_	_	10	μΑ
Terminal capacitar	nce	C_t	V=0, f=1kHz	_	30	250	pF
Collector dark current Collector-emitter breakdown voltage		I_{CEO}	$V_{CE} = 50V, I_{F} = 0$	-	-	100	nA
Collector-emitter breakdown voltage		BV_{CEO}	$I_{C}=0.1 \text{ mA}, I_{F}=0$	80	_	_	V
Emitter-collector breakdown voltage		BV_{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	_	_	V
Collector current		I_{C}	$I_F=5mA$, $V_{CE}=5V$	2.5	_	30.0	mA
Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=20mA$, $I_C=1mA$	_	0.1	0.2	V
Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
Floating capacitance		C_{f}	V=0, f=1MHz	_	0.6	1.0	pF
Cut-off frequency		f_c	V_{CE} =5V, I_{C} =2mA, R_{L} =100 Ω , -3dB	_	80	-	kHz
Rise time		t _r	V 2V I 2m A B 1000	_	4	18	μs
Response time	Fall time	t_{f}	$\mathbf{v}_{\text{CE}}=2\mathbf{v}, \mathbf{I}_{\text{C}}=2\mathbf{m}\mathbf{A}, \mathbf{R}_{\text{L}}=100\mathbf{\Omega}$	-	3	18	μs
	Forward voltage Peak forward voltage Reverse current Terminal capacitat Collector dark cur Collector-emitter breakd Emitter-collector breakd Collector current Collector-emitter saturat Isolation resistance Floating capacitan	Forward voltage Peak forward voltage Reverse current Terminal capacitance Collector dark current Collector-emitter breakdown voltage Emitter-collector breakdown voltage Collector current Collector current Collector-emitter saturation voltage Isolation resistance Floating capacitance Cut-off frequency Response time Response time		Forward voltage V_F $I_F=20mA$ Peak forward voltage V_{FM} $I_{FM}=0.5A$ Reverse current I_R $V_R=4V$ Terminal capacitance C_t $V=0$, $f=1kHz$ Collector dark current I_{CEO} $V_{CE}=50V$, $I_F=0$ Collector-emitter breakdown voltage BV_{CEO} $I_C=0.1mA$, $I_F=0$ Emitter-collector breakdown voltage BV_{ECO} $I_E=10\mu A$, $I_F=0$ Collector current I_C $I_F=5mA$, $V_{CE}=5V$ Collector-emitter saturation voltage V_{CE} (sat) $I_F=20mA$, $I_C=1mA$ Isolation resistance R_{ISO} $DC500V$, 40 to $60\%RH$ Floating capacitance C_f $V=0$, $f=1MHz$ Cut-off frequency f_C $V_{CE}=5V$, $I_C=2mA$, $R_L=100\Omega$, $-3dB$ Response time $I_C=0$ $I_C=0$ $I_C=0$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

^{*1} Pulse width</br>
100µs, Duty ratio: 0.001

2 40 to 60%RH, AC for 1minute, f=60Hz

*3 For 10s



■ Model Line-up

Lead Form	Through-Hole	Wide Through-Hole		I _C [mA]	
Package	Sle	eve	Rank mark	$(I_F=5\text{mA}, V_{CE}=5V, T_a=25^{\circ}\text{C})$	
1 ackage	100pcs	/sleeve			
	PC817XJ0000F	PC817XFJ000F	with or without	2.5 to 30.0	
	PC817X1J000F	PC817XF1J00F	A	4.0 to 8.0	
	PC817X2J000F	PC817XF2J00F	В	6.5 to 13.0	
	PC817X3J000F	PC817XF3J00F	C	10.0 to 20.0	
	PC817X4J000F	PC817XF4J00F	D	15.0 to 30.0	
Model No.	PC817X5J000F	PC817XF5J00F	A or B	4.0 to 13.0	
	PC817X6J000F	PC817XF6J00F	B or C	6.5 to 20.0	
	PC817X7J000F	PC817XF7J00F	C or D	10.0 to 30.0	
	PC817X8J000F	PC817XF8J00F	A, B or C	4.0 to 20.0	
	PC817X9J000F	PC817XF9J00F	B, C or D	6.5 to 30.0	
	PC817X0J000F	PC817XF0J00F	A, B, C or D	4.0 to 30.0	

Lead Form	SMT G	ullwing	Wide SMT Gullwing		I _C [mA] (I _F =5mA, V _{CE} =5V, T _a =25°C)	
Package	Sleeve	Тар	oing	Rank mark		
rackage	100pcs/sleeve	2 000p	cs/reel			
	PC817XIJ000F	PC817XPJ000F	PC817XFPJ00F	with or without	2.5 to 30.0	
	PC817XI1J00F	PC817XP1J00F	_	A	4.0 to 8.0	
	PC817XI2J00F	PC817XP2J00F	_	В	6.5 to 13.0	
	PC817XI3J00F	PC817XP3J00F	_	С	10.0 to 20.0	
	PC817XI4J00F	PC817XP4J00F	_	D	15.0 to 30.0	
Model No.	PC817XI5J00F	PC817XP5J00F	_	A or B	4.0 to 13.0	
	PC817XI6J00F	PC817XP6J00F	-	B or C	6.5 to 20.0	
	PC817XI7J00F	PC817XP7J00F	-	C or D	10.0 to 30.0	
	PC817XI8J00F	PC817XP8J00F	П	A, B or C	4.0 to 20.0	
	PC817XI9J00F	PC817XP9J00F		B, C or D	6.5 to 30.0	
	PC817XI0J00F	PC817XP0J00F	1	A, B, C or D	4.0 to 30.0	

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs. Ambient Temperature

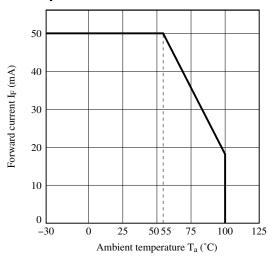


Fig.3 Collector Power Dissipation vs. Ambient Temperature

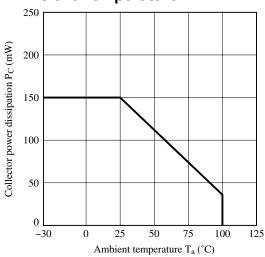


Fig.5 Peak Forward Current vs. Duty Ratio

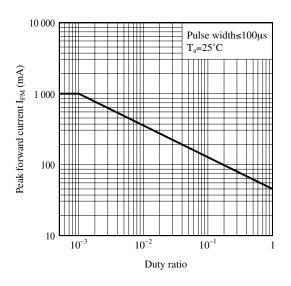


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

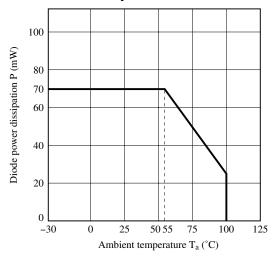


Fig.4 Total Power Dissipation vs. Ambient Temperature

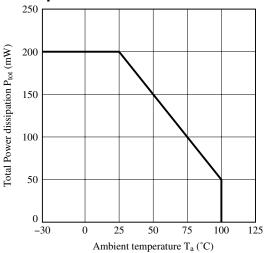


Fig.6 Current Transfer Ratio vs. Forward Current

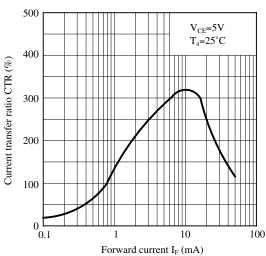




Fig.7 Forward Current vs. Forward Voltage

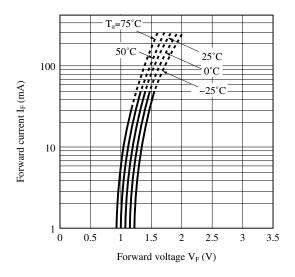


Fig.9 Relative Current Transfer Ratio vs. Ambient Temperature

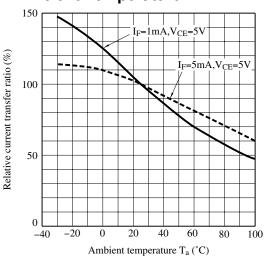


Fig.11 Collector Dark Current vs. Ambient Temperature

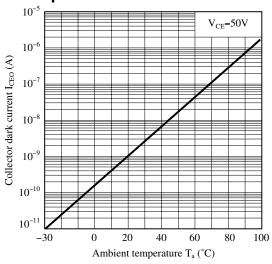


Fig.8 Collector Current vs. Collector-emitter Voltage

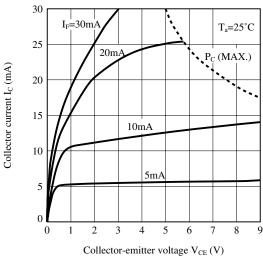


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

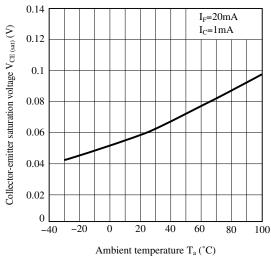
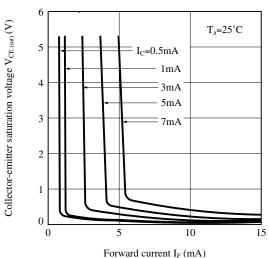


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Sheet No.: D2-A03102EN



Fig.13 Response Time vs. Load Resistance

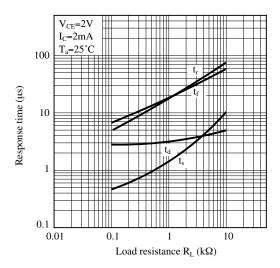


Fig.15 Frequency Response

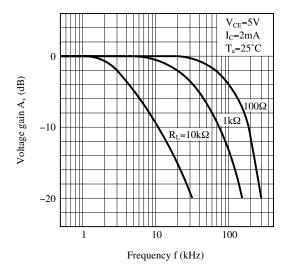
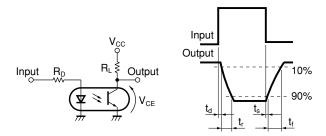
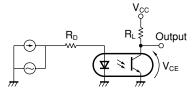


Fig.14 Test Circuit for Response Time



Please refer to the conditions in Fig.13.

Fig.16 Test Circuit for Frequency Response



Please refer to the conditions in Fig.15.

Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

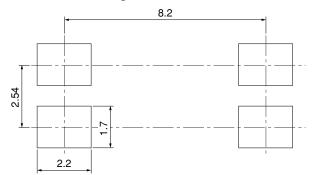
Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

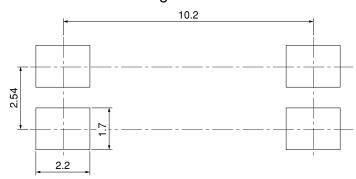
In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended Foot Print (reference)

SMT Gullwing Lead-form



Wide SMT Gullwing Lead-form



(Unit: mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

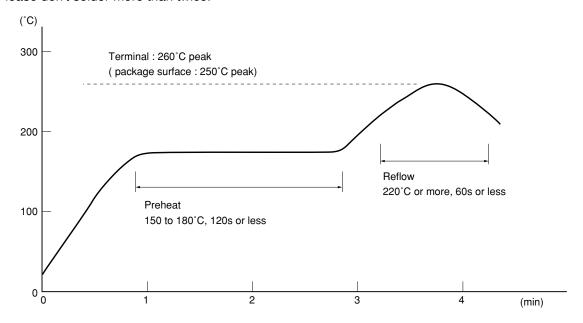
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

Sleeve package

1. Through-Hole or SMT Gullwing Lead-Form

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

Package method

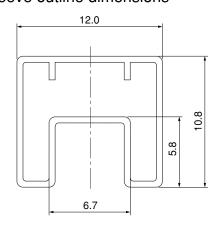
MAX. 100pcs of products shall be packaged in a sleeve.

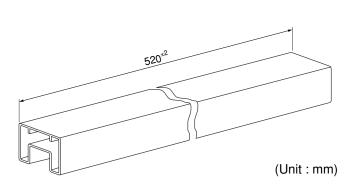
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions





2. Wide Through-Hole Lead-Form or Wide SMT Gullwing Lead-Form

Package materials

Sleeve: HIPS (with anti-static material)

Stopper: Styrene-Elastomer

Package method

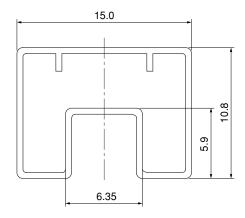
MAX. 100pcs of products shall be packaged in a sleeve.

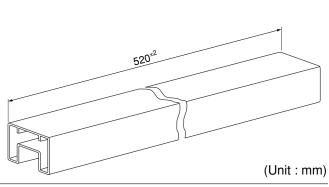
Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side.

MAX. 20 sleeves in one case.

Sleeve outline dimensions





Sheet No.: D2-A03102EN



● Tape and Reel package

1. SMT Gullwing

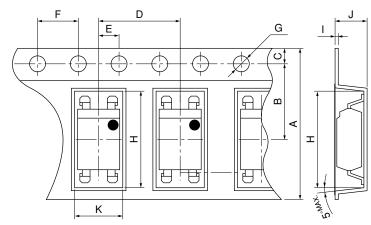
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

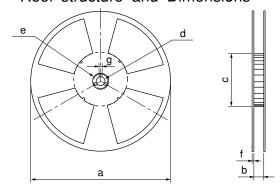
Reel: PS

Carrier tape structure and Dimensions



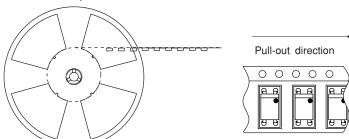
Dimensions List					(U	<u>init : mm)</u>
A	В	С	D	Е	F	G
16.0 ^{±0.3}	7.5 ^{±0.1}	1.75 ^{±0.1}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 + 8.1
Н	I	J	K			
10.4 ^{±0.1}	0.4±0.05	4.2 ^{±0.1}	5.1 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(U	nit : mm)
a	b	c	d
330	17.5 ^{±1.5}	100±1.0	13 ^{±0.5}
e	f	g	
23±1.0	2.0±0.5	2.0 ^{±0.5}	

Direction of product insertion



[Packing: 2 000pcs/reel]



2. Wide SMT Gullwing

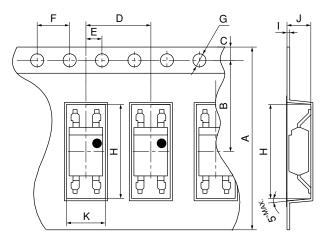
Package materials

Carrier tape: PS

Cover tape: PET (three layer system)

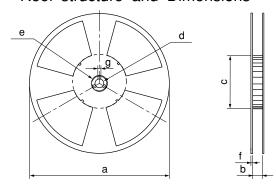
Reel: PS

Carrier tape structure and Dimensions



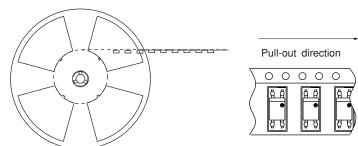
Dimensions List					(U	nit: mm)
A	В	C	D	Е	F	G
24.0±0.3	11.5 ^{±0.1}	1.75 ^{±0.1}	8.0 ^{±0.1}	2.0 ^{±0.1}	4.0 ^{±0.1}	φ1.5 + 8.1
Н	I	J	K			
12.4 ^{±0.1}	0.4 ^{±0.05}	4.1 ^{±0.1}	5.1 ^{±0.1}			

Reel structure and Dimensions



Dimensio	ns List	(U	nit: mm)
a	b	c	d
330 25.5±1.5		100±1.0	13±0.5
e	e f		
23±1.0	2.0±0.5	2.0±0.5	

Direction of product insertion



[Packing: 2 000pcs/reel]



■ Important Notices

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- (i) The devices in this publication are designed for use in general electronic equipment designs such as:
 - --- Personal computers
 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
- (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
 - --- Space applications
 - --- Telecommunication equipment [trunk lines]
 - --- Nuclear power control equipment
 - --- Medical and other life support equipment (e.g., scuba).
- · If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.
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